

Inverter

REJ03D0201-0400Z (Previous ADE-205-016B (Z)) Rev.4.00 Feb.02.2004

Description

The HD74UH04 is high-speed CMOS inverter using silicon gate CMOS process. With CMOS low power dissipation, it provides high-speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

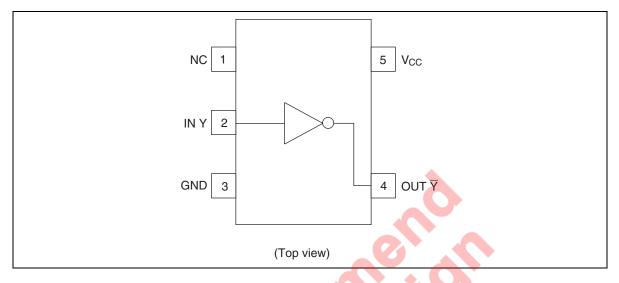
Features

- Encapsulated in very small 5pins package of $2.9 \times 1.6 \times 1.1$ mm, the efficiency to mount on substrate is significantly improved.
- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC04 Supply voltage range: 2 to 6 V Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$
- Ordering Information

			Abbreviation	(Quantity)
HD74UH04EL	MPAK-5 pin	MPAK-5V	_	EL (3,000 pcs/reel)



Pin Arrangement



Article Indication

Marking Lot number
H 5 A

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	
Supply voltage	V _{cc}	-0.5 to +7.0	V	
Input voltage	V _{IN}	–0.5 to V _{CC} +0.5	V	
Output voltage	V _{OUT}	–0.5 to V _{CC} +0.5	V	
Input diode current	l _{IK}	±20	mA	
Output diode current	Ι _{ΟΚ}	±20	mA	
Output current	I _{OUT}	±25	mA	
V _{CC} /GND current	I _{CC} , I _{GND}	±25	mA	
Power dissipation	P _T	200	mW	
Storage temperature	Tstg	-65 to +150	°C	

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Recommended Operating Conditions

Item	Symbol	Ratings	Unit	
Supply voltage	V _{CC}	2 to 6	V	
Input voltage	V _{IN}	0 to V _{CC}	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	Topr	-40 to +85	°C	
Input rise/fall time	t _r , t _f	0 to 1000 (V _{CC} = 2.0 V)	ns	
		0 to 500 ($V_{CC} = 4.5 V$)		
		0 to 400 ($V_{CC} = 6.0 \text{ V}$)		

Electrical Characteristics

Electrical Characteristics											
		V _{CC} Ta = 25°C				Ta = -4	0 to 85°C				
tem	Symbol	(V)	Min	Тур	Max	Min	Max	Unit	Test Con	ditions	
Input voltage	V _{IH}	2.0	1.5		_	1.5	-	V			
		4.5	3.15	—	-	3.15	-6				
		6.0	4.2	—	-	4.2	6	_			
	VIL	2.0	_	-	0.5		0.5	V			
		4.5	_	-6	1.35	_	1.35				
		6.0	-	7	1.8	-	1.8				
Output voltage	V _{OH}	2.0	1.9	2.0		1.9	_	V	$V_{\text{IN}} = V_{\text{IL}}$	I _{OH} = −20 μA	
		4.5	4.4	4.5	6	4.4	_				
		6.0	5.9	6.0	—	5.9	_				
		4.5	4.18	4.31	—	4.31	—			$I_{OH} = -2 \text{ mA}$	
	6	6.0	5.68	5.80	—	5.63	_			I _{OH} = -2.6 mA	
	V _{OL}	2.0		0.0	0.1	_	0.1	V	$V_{\text{IN}} = V_{\text{IH}}$	I _{OL} = 20 μA	
		4.5	_	0.0	0.1	_	0.1	_			
		6.0	—	0.0	0.1	_	0.1	_			
		4.5	_	0.17	0.26	_	0.33	_		$I_{OL} = 2 \text{ mA}$	
		6.0	_	0.18	0.26	_	0.33	_		I _{OL} = 2.6 mA	
Input current	l _{in}	6.0	_	—	±0.1	—	±1.0	μA	$V_{IN} = V_{CC}$	or GND	
Operating current	I _{CC}	6.0	—	—	1.0	—	10.0		$V_{IN} = V_{CC}$	or GND	



Switching Characteristics

 $(C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{CC} = 5 \text{ V})$

		Ta = 2	5°C				
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Output rise/fall time	t _{⊤∟H} t _{⊤H∟}	_	5	10	ns	See Test circuit	
Propagation delay time	t _{PLH} t _{PHL}	_	7	15	ns	See Test circuit	

 $(C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns})$

		Vcc	Ta =	25°C		Ta = -4	0 to 85°C		
Item	Symbol	(V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Output rise/fall time	t _{TLH}	2.0	_	50	125	-	155	ns	See Test circuit
	t _{THL}	4.5	_	14	25	_	31		
		6.0	_	12	21	- 6	26	_	
Propagation delay time	t _{PLH}	2.0	-	48	100	-75	125	ns	See Test circuit
	t _{PHL}	4.5	-	12	20	-	25	_	
		6.0	4	9	17		21	_	
Input capacitance	CIN	-7	-	5	10	_	10	pF	
Equivalent capacitance	C _{PD}	F	_	10	—	_	_	-	

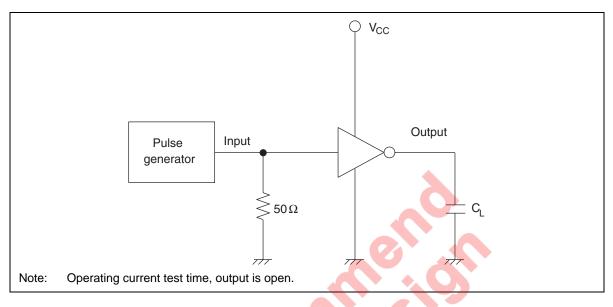
Note: C_{PD} is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

 $I_{CC}(opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

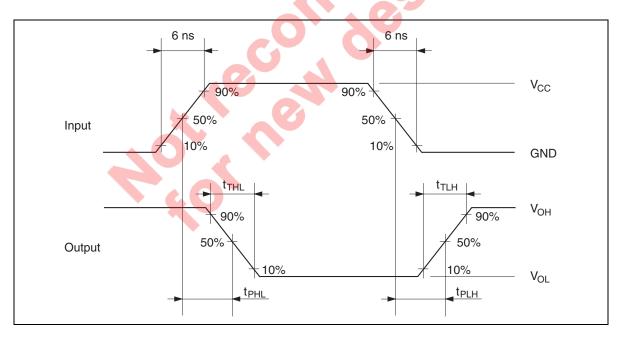
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Test Circuit



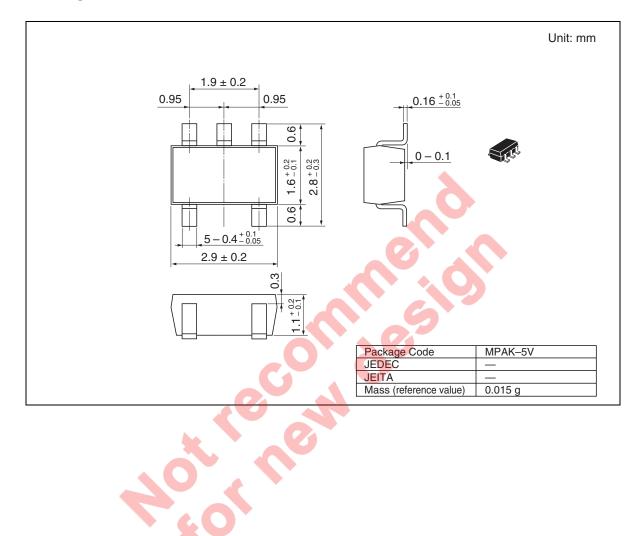
Waveforms



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Package Dimensions >



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